

The documentation and process conversion measures necessary to comply with this revision shall be completed by 20 September 2001.

INCH-POUND

MIL-PRF-19500/702
AMENDMENT 1
21 May 2002

PERFORMANCE SPECIFICATION

SEMICONDUCTOR DEVICE, FIELD EFFECT RADIATION HARDENED
(TOTAL DOSE AND SINGLE EVENT EFFECTS)
TRANSISTOR, N-CHANNEL, SILICON TYPES 2N7482T3, 2N7483T3 AND 2N7484T3
JANTXVR, F, G AND H AND JANSR, F, G AND H

This amendment forms a part of MIL-PRF-19500/702, dated 28 November 2001 and is approved for use by all Departments and Agencies of the Department of Defense.

PAGE 1

1.3, column P_T (1) T_A = +25°C, delete "(1)".

Custodians:
Army - CR
Navy - EC
Air Force - 11
NASA - NA
DLA - CC

Preparing activity:
DLA - CC

(Project 5961-2608)